SN54ABT18245A, SN74ABT18245A SCAN TEST DEVICES WITH 18-BIT BUS TRANSCEIVERS

SCBS110H - AUGUST 1992 - REVISED FEBRUARY 1999

- **Members of the Texas Instruments SCOPE** [™] Family of Testability Products
- **Members of the Texas Instruments** *Widebus*™ Family
- Compatible With the IEEE Standard 1149.1-1990 (JTAG) Test Access Port and **Boundary-Scan Architecture**
- **SCOPE** ™ Instruction Set
 - IEEE Standard 1149.1-1990 Required Instructions, CLAMP and HIGHZ
 - Parallel-Signature Analysis at Inputs
 - Pseudo-Random Pattern Generation **From Outputs**
 - Sample Inputs/Toggle Outputs
 - Binary Count From Outputs
 - Device Identification
 - Even-Parity Opcodes
- State-of-the-Art *EPIC-IIB™* BiCMOS Design Significantly Reduces Power Dissipation
- Packaged in Plastic Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Packages

description

The 'ABT18245A scan test devices with 18-bit bus transceivers are members of the Texas Instruments SCOPE™ testability integratedcircuit family. This family of devices supports IEEE Standard 1149.1-1990 boundary scan to facilitate testing of complex circuit-board assemblies. Scan access to the test circuitry is accomplished via the 4-wire test access port (TAP) interface.

SN54ABT18245A . . . WD PACKAGE SN74ABT18245A...DGG OR DL PACKAGE (TOP VIEW)

				1
1DIR [1	\cup	56	10E
1B1	2		55	1A1
1B2	3		54	1A2
GND[4		53	GND
1B3[5		52	1A3
1B4 [6		51] 1A4
v _{cc} [7		50	Vcc
1B5 [8		49	1A5
1B6	9		48	1A6
1B7	10		47	1A7
GND [11		46	GND
1B8	12		45	1A8
1B9	13		44	1A9
2B1	14		43	2A1
2B2	15		42	2A2
2B3 [16		41	2A3
2B4	17		40	2A4
GND	18		39] GND
2B5	19		38	2A5
2B6	20		37	2A6
2B7	21		36	2A7
Vcc	22		35	V _{CC}
2B8 L	23		34	2A8
2B9 L	24		33	2A9
GND	25		32	GND
2DIR	26		31	20E
TDO [27		30	TDI
TMS	28		29	TCK

In the normal mode, these devices are 18-bit noninverting bus transceivers. They can be used either as two 9-bit transceivers or one 18-bit transceiver. The test circuitry can be activated by the TAP to take snapshot samples of the data appearing at the device pins or to perform a self-test on the boundary-test cells. Activating the TAP in the normal mode does not affect the functional operation of the SCOPE™ bus transceivers.

Data flow is controlled by the direction-control (DIR) and output-enable (OE) inputs. Data transmission is allowed from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at DIR. OE can be used to disable the device so that the buses are effectively isolated.

In the test mode, the normal operation of the SCOPE™ bus transceivers is inhibited and the test circuitry is enabled to observe and control the input/output (I/O) boundary of the device. When enabled, the test circuitry performs boundary-scan test operations according to the protocol described in IEEE Standard 1149.1-1990.



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description (continued)

Four dedicated test pins observe and control the operation of the test circuitry: test-data input (TDI), test-data output (TDO), test-mode select (TMS), and test clock (TCK). Additionally, the test circuitry performs other testing functions such as parallel-signature analysis (PSA) on data inputs and pseudo-random pattern generation (PRPG) from data outputs. All testing and scan operations are synchronized to the TAP interface.

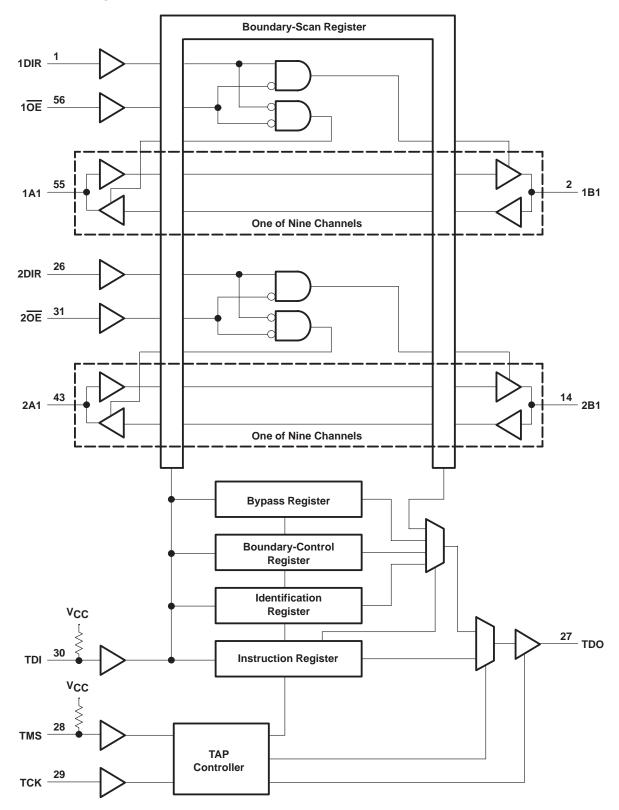
The SN54ABT18245A is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74ABT18245A is characterized for operation from -40° C to 85° C.

FUNCTION TABLE (normal mode, each 9-bit section)

INP	UTS	ODEDATION			
ŌE	DIR	OPERATION			
L	L	B data to A bus			
L	Н	A data to B bus			
Н	Χ	Isolation			



functional block diagram





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Terminal Functions

TERMINAL NAME	DESCRIPTION
1A1–1A9, 2A1–2A9	Normal-function A-bus I/O ports. See function table for normal-mode logic.
1B1–1B9, 2B1–2B9	Normal-function B-bus I/O ports. See function table for normal-mode logic.
1DIR, 2DIR	Normal-function direction controls. See function table for normal-mode logic.
GND	Ground
10E, 20E	Normal-function output enables. See function table for normal-mode logic.
тск	Test clock. One of four terminals required by IEEE Standard 1149.1-1990. Test operations of the device are synchronous to TCK. Data is captured on the rising edge of TCK and outputs change on the falling edge of TCK.
TDI	Test data input. One of four terminals required by IEEE Standard 1149.1-1990. TDI is the serial input for shifting data through the instruction register or selected data register. An internal pullup forces TDI to a high level if left unconnected.
TDO	Test data output. One of four terminals required by IEEE Standard 1149.1-1990. TDO is the serial output for shifting data through the instruction register or selected data register.
TMS	Test mode select. One of four terminals required by IEEE Standard 1149.1-1990. TMS directs the device through its TAP controller states. An internal pullup forces TMS to a high level if left unconnected.
VCC	Supply voltage



test architecture

Serial-test information is conveyed by means of a 4-wire test bus, or TAP, that conforms to IEEE Standard 1149.1-1990. Test instructions, test data, and test control signals all are passed along this serial-test bus. The TAP controller monitors two signals from the test bus, TCK and TMS. The TAP controller extracts the synchronization (TCK) and state control (TMS) signals from the test bus and generates the appropriate on-chip control signals for the test structures in the device. Figure 1 shows the TAP-controller state diagram.

The TAP controller is fully synchronous to the TCK signal. Input data is captured on the rising edge of TCK and output data changes on the falling edge of TCK. This scheme ensures that data to be captured is valid for fully one-half of the TCK cycle.

The functional block diagram illustrates the IEEE Standard 1149.1-1990 4-wire test bus and boundary-scan architecture and the relationship among the test bus, the TAP controller, and the test registers. As illustrated, the device contains an 8-bit instruction register and four test-data registers: a 44-bit boundary-scan register, a 3-bit boundary-control register, a 1-bit bypass register, and a 32-bit device-identification register.

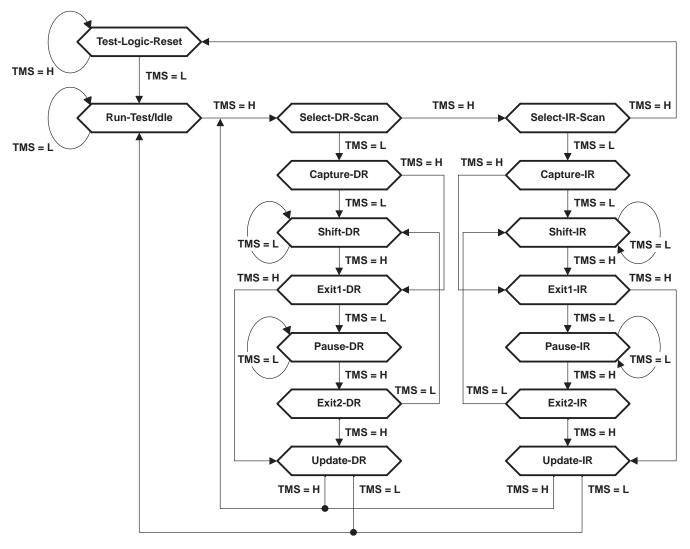


Figure 1. TAP-Controller State Diagram



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state diagram description

The TAP controller is a synchronous finite-state machine that provides test control signals throughout the device. The state diagram shown in Figure 1 is in accordance with IEEE Standard 1149.1-1990. The TAP controller proceeds through its states based on the level of TMS at the rising edge of TCK.

As shown, the TAP controller consists of 16 states. There are six stable states (indicated by a looping arrow in the state diagram) and ten unstable states. A stable state is a state the TAP controller can retain for consecutive TCK cycles. Any state that does not meet this criterion is an unstable state.

There are two main paths through the state diagram: one to access and control the selected data register and one to access and control the instruction register. Only one register can be accessed at a time.

Test-Logic-Reset

The device powers up in the Test-Logic-Reset state. In the stable Test-Logic-Reset state, the test logic is reset and is disabled so that the normal logic function of the device is performed. The instruction register is reset to an opcode that selects the optional IDCODE instruction, if supported, or the BYPASS instruction. Certain data registers also can be reset to their power-up values.

The state machine is constructed such that the TAP controller returns to the Test-Logic-Reset state in no more than five TCK cycles if TMS is left high. TMS has an internal pullup resistor that forces it high if left unconnected or if a board defect causes it to be open circuited.

For the 'ABT18245A, the instruction register is reset to the binary value 10000001, which selects the IDCODE instruction. Bits 43-40 in the boundary-scan register are reset to logic 0, ensuring that these cells, which control the A-port and B-port outputs are set to benign values (i.e., if test mode were invoked, the outputs would be at the high-impedance state). Reset values of other bits in the boundary-scan register should be considered indeterminate. The boundary-control register is reset to the binary value 010, which selects the PSA test operation.

Run-Test/Idle

The TAP controller must pass through the Run-Test/Idle state (from Test-Logic-Reset) before executing any test operations. The Run-Test/Idle state also can be entered following data-register or instruction-register scans. Run-Test/Idle is a stable state in which the test logic actively can be running a test or can be idle. The test operations selected by the boundary-control register are performed while the TAP controller is in the Run-Test/Idle state.

Select-DR-Scan, Select-IR-Scan

No specific function is performed in the Select-DR-Scan and Select-IR-Scan states, and the TAP controller exits either of these states on the next TCK cycle. These states allow the selection of either data-register scan or instruction-register scan.

Capture-DR

When a data-register scan is selected, the TAP controller must pass through the Capture-DR state. In the Capture-DR state, the selected data register can capture a data value as specified by the current instruction. Such capture operations occur on the rising edge of TCK, upon which the TAP controller exits the Capture-DR state.



Shift-DR

Upon entry to the Shift-DR state, the data register is placed in the scan path between TDI and TDO. On the first falling edge of TCK, TDO goes from the high-impedance state to an active state. TDO enables to the logic level present in the least significant bit of the selected data register.

While in the stable Shift-DR state, data is serially shifted through the selected data register on each TCK cycle. The first shift occurs on the first rising edge of TCK after entry to the Shift-DR state (i.e., no shifting occurs during the TCK cycle in which the TAP controller changes from Capture-DR to Shift-DR or from Exit2-DR to Shift-DR). The last shift occurs on the rising edge of TCK, upon which the TAP controller exits the Shift-DR state.

Exit1-DR, Exit2-DR

The Exit1-DR and Exit2-DR states are temporary states that end a data-register scan. It is possible to return to the Shift-DR state from either Exit1-DR or Exit2-DR without recapturing the data register. On the first falling edge of TCK after entry to Exit1-DR, TDO goes from the active state to the high-impedance state.

Pause-DR

No specific function is performed in the stable Pause-DR state, in which the TAP controller can remain indefinitely. The Pause-DR state suspends and resumes data-register scan operations without loss of data.

Update-DR

If the current instruction calls for the selected data register to be updated with current data, such updates occur on the falling edge of TCK, following entry to the Update-DR state.

Capture-IR

When an instruction-register scan is selected, the TAP controller must pass through the Capture-IR state. In the Capture-IR state, the instruction register captures its current status value. This capture operation occurs on the rising edge of TCK, upon which the TAP controller exits the Capture-IR state. For the 'ABT18245A, the status value loaded in the Capture-IR state is the fixed binary value 10000001.

Shift-IR

Upon entry to the Shift-IR state, the instruction register is placed in the scan path between TDI and TDO. On the first falling edge of TCK, TDO goes from the high-impedance state to an active state. TDO enables to the logic level present in the least significant bit of the instruction register.

While in the stable Shift-IR state, instruction data is serially shifted through the instruction register on each TCK cycle. The first shift occurs on the first rising edge of TCK after entry to the Shift-IR state (i.e., no shifting occurs during the TCK cycle in which the TAP controller changes from Capture-IR to Shift-IR or from Exit2-IR to Shift-IR). The last shift occurs on the rising edge of TCK, upon which the TAP controller exits the Shift-IR state.

Exit1-IR, Exit2-IR

The Exit1-IR and Exit2-IR states are temporary states that end an instruction-register scan. It is possible to return to the Shift-IR state from either Exit1-IR or Exit2-IR without recapturing the instruction register. On the first falling edge of TCK after entry to Exit1-IR, TDO goes from the active state to the high-impedance state.

Pause-IR

No specific function is performed in the stable Pause-IR state, in which the TAP controller can remain indefinitely. The Pause-IR state suspends and resumes instruction-register scan operations without loss of data.

Update-IR

The current instruction is updated and takes effect on the falling edge of TCK, following entry to the Update-IR state.



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register overview

With the exception of the bypass and device-identification registers, any test register can be thought of as a serial-shift register with a shadow latch on each bit. The bypass and device-identification registers differ in that they contain only a shift register. During the appropriate capture state (Capture-IR for instruction register, Capture-DR for data registers), the shift register can be parallel loaded from a source specified by the current instruction. During the appropriate shift state (Shift-IR or Shift-DR), the contents of the shift register are shifted out from TDO while new contents are shifted in at TDI. During the appropriate update state (Update-IR or Update-DR), the shadow latches are updated from the shift register.

instruction register description

The instruction register (IR) is eight bits long and tells the device what instruction is to be executed. Information contained in the instruction includes the mode of operation (either normal mode, in which the device performs its normal logic function, or test mode, in which the normal logic function is inhibited or altered), the test operation to be performed, which of the four data registers is to be selected for inclusion in the scan path during data-register scans, and the source of data to be captured into the selected data register during Capture-DR.

Table 3 lists the instructions supported by the 'ABT18245A. The even-parity feature specified for SCOPE™ devices is supported in this device. Bit 7 of the instruction opcode is the parity bit. Any instructions that are defined for SCOPE™ devices but are not supported by this device default to BYPASS.

During Capture-IR, the IR captures the binary value 10000001. As an instruction is shifted in, this value is shifted out via TDO and can be inspected as verification that the IR is in the scan path. During Update-IR, the value that has been shifted into the IR is loaded into shadow latches. At this time, the current instruction is updated and any specified mode change takes effect. At power up or in the Test-Logic-Reset state, the IR is reset to the binary value 10000001, which selects the IDCODE instruction. The IR order of scan is shown in Figure 2.

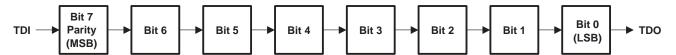


Figure 2. Instruction Register Order of Scan



data register description

boundary-scan register

The boundary-scan register (BSR) is 44 bits long. It contains one boundary-scan cell (BSC) for each normal-function input pin, one BSC for each normal-function I/O pin (one single cell for both input data and output data), and one BSC for each of the internally decoded output-enable signals (10EA, 20EA, 10EB, 20EB). The BSR is used to store test data that is to be applied externally to the device output pins, and/or to capture data that appears internally at the outputs of the normal on-chip logic and/or externally at the device input pins.

The source of data to be captured into the BSR during Capture-DR is determined by the current instruction. The contents of the BSR can change during Run-Test/Idle, as determined by the current instruction. At power up or in Test-Logic-Reset, BSCs 43–40 are reset to logic 0, ensuring that these cells, which control A-port and B-port outputs, are set to benign values (i.e., if test mode were invoked, the outputs would be at the high-impedance state). Reset values of other BSCs should be considered indeterminate.

When external data is to be captured, the BSCs for signals 10EA, 20EA, 10EB, and 20EB capture logic values determined by the following positive-logic equations: 10EA = 10E • 1DIR, 20EA = 20E • 2DIR, 10EB = 10E • DIR, and 20EB = 20E • DIR. When data is to be applied externally, these BSCs control the drive state (active or high impedance) of their respective outputs.

The BSR order of scan is from TDI through bits 43–0 to TDO. Table 1 shows the BSR bits and their associated device pin signals.

BSR BIT NUMBER	DEVICE SIGNAL								
43	20EB	35	2A9-I/O	26	1A9-I/O	17	2B9-I/O	8	1B9-I/O
42	10EB	34	2A8-I/O	25	1A8-I/O	16	2B8-I/O	7	1B8-I/O
41	20EA	33	2A7-I/O	24	1A7-I/O	15	2B7-I/O	6	1B7-I/O
40	10EA	32	2A6-I/O	23	1A6-I/O	14	2B6-I/O	5	1B6-I/O
39	2DIR	31	2A5-I/O	22	1A5-I/O	13	2B5-I/O	4	1B5-I/O
38	1DIR	30	2A4-I/O	21	1A4-I/O	12	2B4-I/O	3	1B4-I/O
37	2OE	29	2A3-I/O	20	1A3-I/O	11	2B3-I/O	2	1B3-I/O
36	1OE	28	2A2-I/O	19	1A2-I/O	10	2B2-I/O	1	1B2-I/O
_		27	2A1-I/O	18	1A1-I/O	9	2B1-I/O	0	1B1-I/O

Table 1. Boundary-Scan Register Configuration

boundary-control register

The boundary-control register (BCR) is three bits long. The BCR is used in the context of the boundary-run test (RUNT) instruction to implement additional test operations not included in the basic SCOPE™ instruction set. Such operations include PRPG, PSA, and binary count up (COUNT). Table 4 shows the test operations that are decoded by the BCR.

During Capture-DR, the contents of the BCR are not changed. At power up or in Test-Logic-Reset, the BCR is reset to the binary value 010, which selects the PSA test operation. The BCR order of scan is shown in Figure 3.

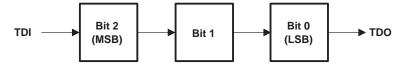


Figure 3. Boundary-Control Register Order of Scan



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bypass register

The bypass register is a 1-bit scan path that can be selected to shorten the length of the system scan path, reducing the number of bits per test pattern that must be applied to complete a test operation. During Capture-DR, the bypass register captures a logic 0. The bypass register order of scan is shown in Figure 4.

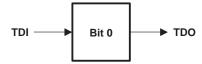


Figure 4. Bypass Register Order of Scan

device-identification register

The device-identification register (IDR) is 32 bits long. It can be selected and read to identify the manufacturer, part number, and version of this device.

During Capture-DR, the binary value 0001000000000001011000000101111 (1000502F, hex) is captured in the IDR to identify this device as Texas Instruments SN54/74ABT18245A. The IDR order of scan is from TDI through bits 31–0 to TDO. Table 2 shows the IDR bits and their significance.

Table 2. Device-Identification Register Configuration

IDR BIT NUMBER	IDENTIFICATION SIGNIFICANCE	IDR BIT NUMBER	IDENTIFICATION SIGNIFICANCE	IDR BIT NUMBER	IDENTIFICATION SIGNIFICANCE
31	VERSION3	27	PARTNUMBER15	11	MANUFACTURER10 [†]
30	VERSION2	26	PARTNUMBER14	10	MANUFACTURER09 [†]
29	VERSION1	25	PARTNUMBER13	9	MANUFACTURER08 [†]
28	VERSION0	24	PARTNUMBER12	8	MANUFACTURER07 [†]
_	_	23	PARTNUMBER11	7	MANUFACTURER06 [†]
_	_	22	PARTNUMBER10	6	MANUFACTURER05 [†]
_	_	21	PARTNUMBER09	5	MANUFACTURER04 [†]
_	_	20	PARTNUMBER08	4	MANUFACTURER03 [†]
_	_	19	PARTNUMBER07	3	MANUFACTURER02 [†]
_	_	18	PARTNUMBER06	2	MANUFACTURER01 [†]
_	_	17	PARTNUMBER05	1	MANUFACTURER00†
_	_	16	PARTNUMBER04	0	LOGIC1 [†]
_	_	15	PARTNUMBER03	_	_
	_	14	PARTNUMBER02		_
	_	13	PARTNUMBER01	_	_
_	_	12	PARTNUMBER00	_	_

[†]Note that for TI products, bits 11-0 of the device-identification register always contain the binary value 000000101111 (02F, hex).



instruction-register opcode description

The instruction-register opcodes are shown in Table 3. The following descriptions detail the operation of each instruction.

Table 3. Instruction-Register Opcodes

BINARY CODE† BIT $7 \rightarrow$ BIT 0 MSB \rightarrow LSB	SCOPE OPCODE	DESCRIPTION	SELECTED DATA REGISTER	MODE
00000000	EXTEST	Boundary scan	Boundary scan	Test
10000001	IDCODE	Identification read	Device identification	Normal
10000010	SAMPLE/PRELOAD	Sample boundary	Boundary scan	Normal
00000011	BYPASS [‡]	Bypass scan	Bypass	Normal
10000100	BYPASS [‡]	Bypass scan	Bypass	Normal
00000101	BYPASS [‡]	Bypass scan	Bypass	Normal
00000110	HIGHZ	Control boundary to high impedance	Bypass	Modified test
10000111	CLAMP	Control boundary to 1/0	Bypass	Test
10001000	BYPASS‡	Bypass scan	Bypass	Normal
00001001	RUNT	Boundary-run test	Bypass	Test
00001010	READBN	Boundary read	Boundary scan	Normal
10001011	READBT	Boundary read	Boundary scan	Test
00001100	CELLTST	Boundary self test	Boundary scan	Normal
10001101	TOPHIP	Boundary toggle outputs	Bypass	Test
10001110	SCANCN	Boundary-control register scan	Boundary control	Normal
00001111	SCANCT	Boundary-control register scan	Boundary control	Test
All others	BYPASS	Bypass scan	Bypass	Normal

[†] Bit 7 is used to maintain even parity in the 8-bit instruction.

boundary scan

This instruction conforms to the IEEE Standard 1149.1-1990 EXTEST instruction. The BSR is selected in the scan path. Data appearing at the device input and I/O pins is captured in the associated BSCs. Data that has been scanned into the input BSCs is applied to the inputs of the normal on-chip logic, while data scanned into the I/O BSCs for pins in the output mode is applied to the device I/O pins. Data present at the device I/O pins is passed through the I/O BSCs to the normal on-chip logic. For I/O pins, the operation of a pin as input or output is determined by the contents of the output-enable BSCs (bits 43–40 of the BSR). When a given output enable is active (logic 1), the associated I/O pins operate in the output mode. Otherwise, the I/O pins operate in the input mode. The device operates in the test mode.

identification read

This instruction conforms to the IEEE Standard 1149.1-1990 IDCODE instruction. The IDR is selected in the scan path. The device operates in the normal mode.

sample boundary

This instruction conforms to the IEEE Standard 1149.1-1990 SAMPLE/PRELOAD instruction. The BSR is selected in the scan path. Data appearing at the device input pins and I/O pins in the input mode is captured in the associated BSCs, while data appearing at the outputs of the normal on-chip logic is captured in the BSCs associated with I/O pins in the output mode. The device operates in the normal mode.



[‡] The BYPASS instruction is executed in lieu of a SCOPE™ instruction that is not supported in the 'ABT18245A.

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bypass scan

This instruction conforms to the IEEE Standard 1149.1-1990 BYPASS instruction. The bypass register is selected in the scan path. A logic 0 value is captured in the bypass register during Capture-DR. The device operates in the normal mode.

control boundary to high impedance

This instruction conforms to the IEEE Standard 1149.1a-1993 HIGHZ instruction. The bypass register is selected in the scan path. A logic 0 value is captured in the bypass register during Capture-DR. The device operates in a modified test mode in which all device I/O pins are placed in the high-impedance state, the device input pins remain operational, and the normal on-chip logic function is performed.

control boundary to 1/0

This instruction conforms to the IEEE Standard 1149.1a-1993 CLAMP instruction. The bypass register is selected in the scan path. A logic 0 value is captured in the bypass register during Capture-DR. Data in the input BSCs is applied to the inputs of the normal on-chip logic, while data in the I/O BSCs for pins in the output mode is applied to the device I/O pins. The device operates in the test mode.

boundary-run test

The bypass register is selected in the scan path. A logic 0 value is captured in the bypass register during Capture-DR. The device operates in the test mode. The test operation specified in the BCR is executed during Run-Test/Idle. The five test operations decoded by the BCR are: sample inputs/toggle outputs (TOPSIP), PRPG, PSA, simultaneous PSA and PRPG (PSA/PRPG), and simultaneous PSA and binary count up (PSA/COUNT).

boundary read

The BSR is selected in the scan path. The value in the BSR remains unchanged during Capture-DR. This instruction is useful for inspecting data after a PSA operation.

boundary self test

The BSR is selected in the scan path. All BSCs capture the inverse of their current values during Capture-DR. In this way, the contents of the shadow latches can be read out to verify the integrity of both shift-register and shadow-latch elements of the BSR. The device operates in the normal mode.

boundary toggle outputs

The bypass register is selected in the scan path. A logic 0 value is captured in the bypass register during Capture-DR. Data in the shift-register elements of the selected output-mode BSCs is toggled on each rising edge of TCK in Run-Test/Idle, updated in the shadow latches, and applied to the associated device I/O pins on each falling edge of TCK in Run-Test/Idle. Data in the input-mode BSCs remains constant. Data appearing at the device input or I/O pins is not captured in the input-mode BSCs. The device operates in the test mode.

boundary-control-register scan

The BCR is selected in the scan path. The value in the BCR remains unchanged during Capture-DR. This operation must be performed before a boundary-run test operation to specify which test operation is to be executed.



boundary-control-register opcode description

The BCR opcodes are decoded from BCR bits 2–0 as shown in Table 4. The selected test operation is performed while the RUNT instruction is executed in the Run-Test/Idle state. The following descriptions detail the operation of each BCR instruction and illustrate the associated PSA and PRPG algorithms.

Table 4. Boundary-Control Register Opcodes

$\begin{array}{c} \text{BINARY CODE} \\ \text{BIT 2} \rightarrow \text{BIT 0} \\ \text{MSB} \rightarrow \text{LSB} \end{array}$	DESCRIPTION
X00	Sample inputs/toggle outputs (TOPSIP)
X01	Pseudo-random pattern generation/36-bit mode (PRPG)
X10	Parallel-signature analysis/36-bit mode (PSA)
011	Simultaneous PSA and PRPG/18-bit mode (PSA/PRPG)
111	Simultaneous PSA and binary count up/18-bit mode (PSA/COUNT)

While the control input BSCs (bits 43–36) are not included in the toggle, PSA, PRPG, or COUNT algorithms, the output-enable BSCs (bits 43–40 of the BSR) control the drive state (active or high impedance) of the selected device output pins. These BCR instructions are valid only when both bytes of the device are operating in one direction of data flow (i.e., $10EA \neq 10EB$ and $20EA \neq 20EB$) and in the same direction of data flow (i.e., 10EA = 20EA and 10EB = 20EB). Otherwise, the bypass instruction is operated.

sample inputs/toggle outputs (TOPSIP)

Data appearing at the selected device input-mode I/O pins is captured in the shift-register elements of the associated BSCs on each rising edge of TCK. Data in the shift-register elements of the selected output-mode BSCs is toggled on each rising edge of TCK, updated in the shadow latches, and applied to the associated device I/O pins on each falling edge of TCK.

pseudo-random pattern generation (PRPG)

A pseudo-random pattern is generated in the shift-register elements of the selected BSCs on each rising edge of TCK, updated in the shadow latches, and applied to the associated device output-mode I/O pins on each falling edge of TCK. Figures 5 and 6 illustrate the 36-bit linear-feedback shift-register algorithms through which the patterns are generated. An initial seed value should be scanned into the BSR before performing this operation. A seed value of all zeroes does not produce additional patterns.

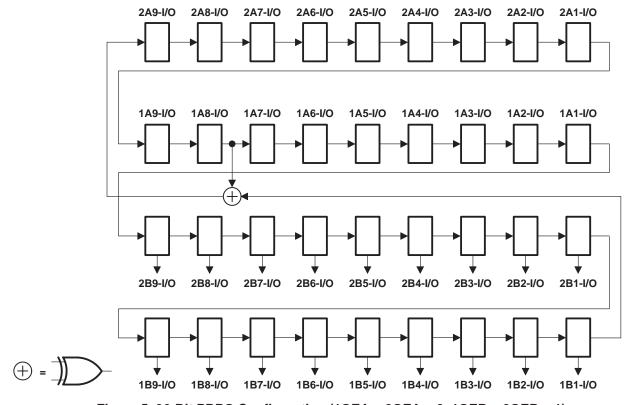


Figure 5. 36-Bit PRPG Configuration (10EA = 20EA = 0, 10EB = 20EB = 1)



pseudo-random pattern generation (PRPG) (continued)

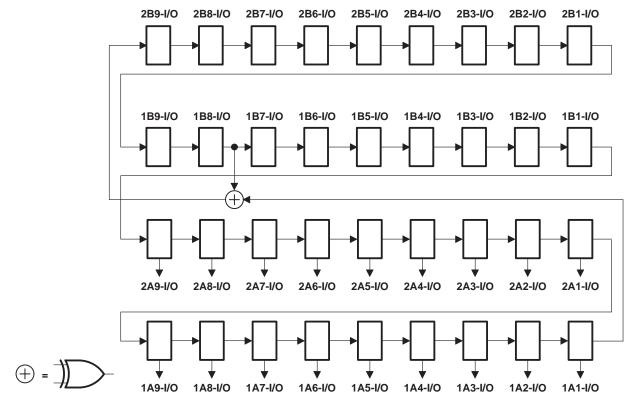


Figure 6. 36-Bit PRPG Configuration (10EA = 20EA = 1, 10EB = 20EB = 0)



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parallel-signature analysis (PSA)

Data appearing at the selected device input-mode I/O pins is compressed into a 36-bit parallel signature in the shift-register elements of the selected BSCs on each rising edge of TCK. Data in the shadow latches of the selected output-mode BSCs remains constant and is applied to the associated device I/O pins. Figures 7 and 8 illustrate the 36-bit linear-feedback shift-register algorithms through which the signature is generated. An initial seed value should be scanned into the BSR before performing this operation.

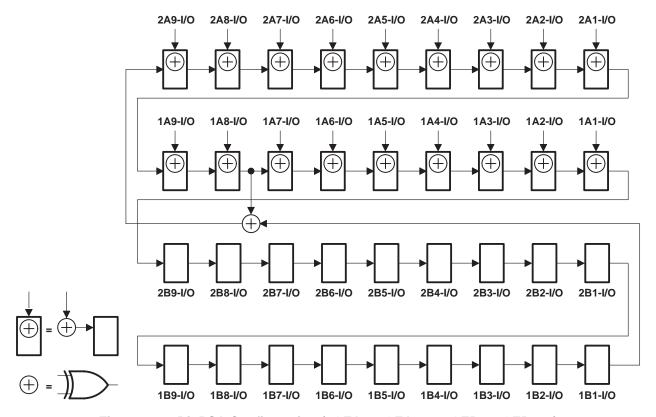


Figure 7. 36-Bit PSA Configuration (10EA = 20EA = 0, 10EB = 20EB = 1)



parallel-signature analysis (PSA) (continued)

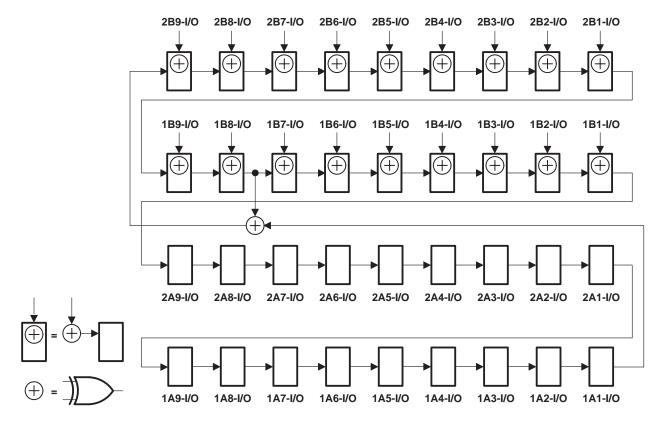


Figure 8. 36-Bit PSA Configuration (10EA = 20EA = 1, 10EB = 20EB = 0)

simultaneous PSA and PRPG (PSA/PRPG)

Data appearing at the selected device input-mode I/O pins is compressed into an 18-bit parallel signature in the shift-register elements of the selected input-mode BSCs on each rising edge of TCK. At the same time, an 18-bit pseudo-random pattern is generated in the shift-register elements of the selected output-mode BSCs on each rising edge of TCK, updated in the shadow latches, and applied to the associated device I/O pins on each falling edge of TCK. Figures 9 and 10 illustrate the 18-bit linear-feedback shift-register algorithms through which the signature and patterns are generated. An initial seed value should be scanned into the BSR before performing this operation. A seed value of all zeroes does not produce additional patterns.

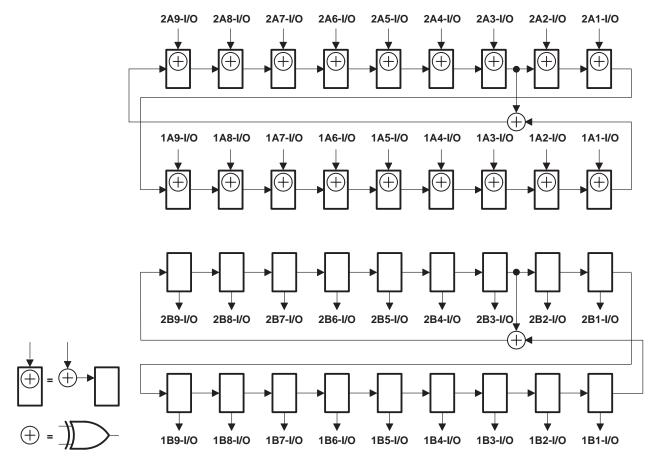


Figure 9. 18-Bit PSA/PRPG Configuration (10EA = 20EA = 0, 10EB = 20EB = 1)



simultaneous PSA and PRPG (PSA/PRPG) (continued)

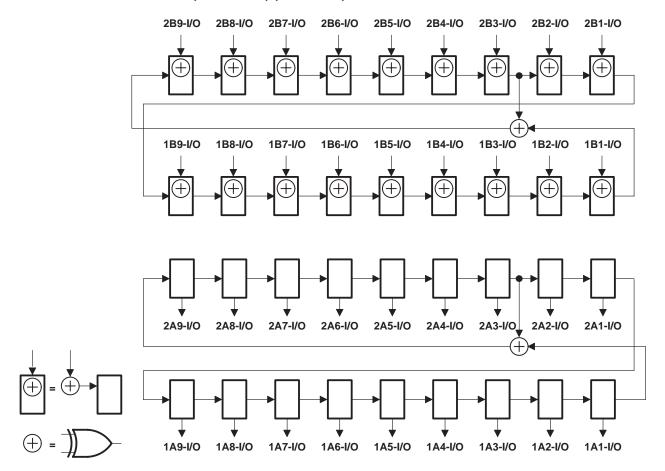


Figure 10. 18-Bit PSA/PRPG Configuration (10EA = 20EA = 1, 10EB = 20EB = 0)

simultaneous PSA and binary count up (PSA/COUNT)

Data appearing at the selected device input-mode I/O pins is compressed into an 18-bit parallel signature in the shift-register elements of the selected input-mode BSCs on each rising edge of TCK. At the same time, an 18-bit binary count-up pattern is generated in the shift-register elements of the selected output-mode BSCs on each rising edge of TCK, updated in the shadow latches, and applied to the associated device I/O pins on each falling edge of TCK. Figures 11 and 12 illustrate the 18-bit linear-feedback shift-register algorithms through which the signature is generated. An initial seed value should be scanned into the BSR before performing this operation.

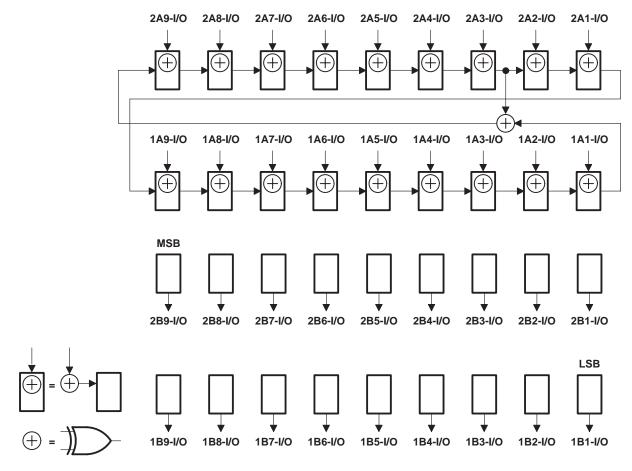


Figure 11. 18-Bit PSA/COUNT Configuration (10EA = 20EA = 0, 10EB = 20EB = 1)



simultaneous PSA and binary count up (PSA/COUNT) (continued)

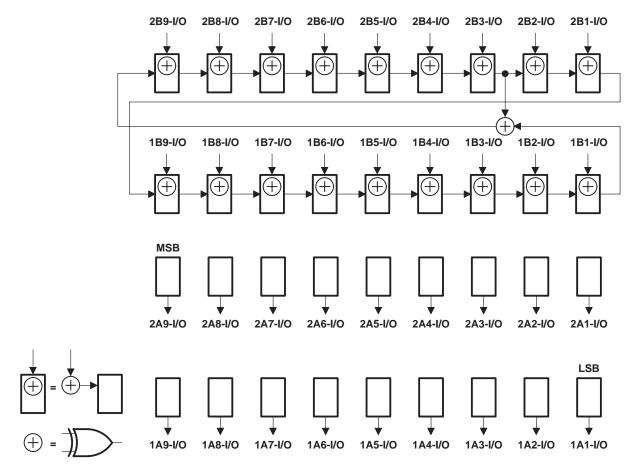


Figure 12. 18-Bit PSA/COUNT Configuration (10EA = 20EA = 1, 10EB = 20EB = 0)

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timing description

All test operations of the 'ABT18245A are synchronous to TCK. Data on the TDI, TMS, and normal-function inputs is captured on the rising edge of TCK. Data appears on the TDO and normal-function output pins on the falling edge of TCK. The TAP controller is advanced through its states (as shown in Figure 1) by changing the value of TMS on the falling edge of TCK and then applying a rising edge to TCK.

A simple timing example is shown in Figure 13. In this example, the TAP controller begins in the Test-Logic-Reset state and is advanced through its states, as necessary, to perform one instruction-register scan and one data-register scan. While in the Shift-IR and Shift-DR states, TDI is used to input serial data and TDO is used to output serial data. The TAP controller is then returned to the Test-Logic-Reset state. Table 5 details the operation of the test circuitry during each TCK cycle.

Table 5. Explanation of Timing Example

TCK CYCLE(S)	TAP STATE AFTER TCK	DESCRIPTION
1	Test-Logic-Reset	TMS is changed to a logic 0 value on the falling edge of TCK to begin advancing the TAP controller toward the desired state.
2	Run-Test/Idle	
3	Select-DR-Scan	
4	Select-IR-Scan	
5	Capture-IR	The IR captures the 8-bit binary value 10000001 on the rising edge of TCK as the TAP controller exits the Capture-IR state.
6	Shift-IR	TDO becomes active and TDI is made valid on the falling edge of TCK. The first bit is shifted into the TAP on the rising edge of TCK as the TAP controller advances to the next state.
7–13	Shift-IR	One bit is shifted into the IR on each TCK rising edge. With TDI held at a logic 1 value, the 8-bit binary value 11111111 is serially scanned into the IR. At the same time, the 8-bit binary value 10000001 is serially scanned out of the IR via TDO. In TCK cycle 13, TMS is changed to a logic 1 value to end the IR scan on the next TCK cycle. The last bit of the instruction is shifted as the TAP controller advances from Shift-IR to Exit1-IR.
14	Exit1-IR	TDO becomes inactive (goes to the high-impedance state) on the falling edge of TCK.
15	Update-IR	The IR is updated with the new instruction (BYPASS) on the falling edge of TCK.
16	Select-DR-Scan	
17	Capture-DR	The bypass register captures a logic 0 value on the rising edge of TCK as the TAP controller exits the Capture-DR state.
18	Shift-DR	TDO becomes active and TDI is made valid on the falling edge of TCK. The first bit is shifted into the TAP on the rising edge of TCK as the TAP controller advances to the next state.
19–20	Shift-DR	The binary value 101 is shifted in via TDI, while the binary value 010 is shifted out via TDO.
21	Exit1-DR	TDO becomes inactive (goes to the high-impedance state) on the falling edge of TCK.
22	Update-DR	The selected data register is updated with the new data on the falling edge of TCK.
23	Select-DR-Scan	
24	Select-IR-Scan	
25	Test-Logic-Reset	Test operation completed



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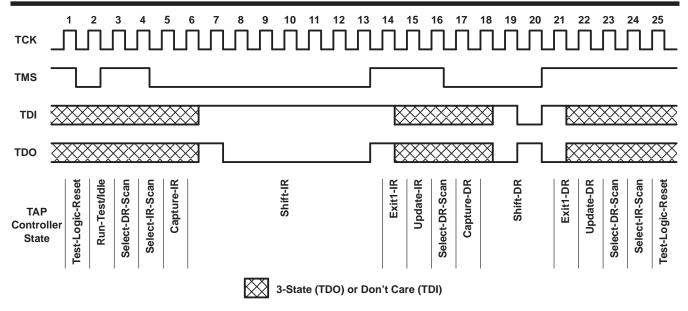


Figure 13. Timing Example

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (except I/O ports) (see Note 1)	–0.5 V to 7 V
Input voltage range, V _I (I/O ports) (see Note 1)	0.5 V to 5.5 V
Voltage range applied to any output in the high state or power-off state, VO	
Current into any output in the low state, IO: SN54ABT18245A	96 mA
SN74ABT18245A	128 mA
Input clamp current, I _{IK} (V _I < 0)	–18 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous current through V _{CC}	576 mA
Continuous current through GND	1152 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	81°C/W
	74°C/W
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings can be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.



SN54ABT18245A, SN74ABT18245A SCAN TEST DEVICES WITH 18-BIT BUS TRANSCEIVERS

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recommended operating conditions (see Note 3)

		SN54ABT18245A SN74			SN74ABT18245A		
		MIN	MAX	MIN	MAX	UNIT	
Vсс	Supply voltage	4.5	5.5	4.5	5.5	V	
VIH	High-level input voltage	2		2		V	
V _I L	Low-level input voltage		0.8		0.8	V	
VI	Input voltage	0	Vcc	0	Vcc	V	
IOH	High-level output current		-24		-32	mA	
IOL	Low-level output current		48		64	mA	
Δt/Δν	Input transition rise or fall rate		10		10	ns/V	
TA	Operating free-air temperature	-55	125	-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TECT	CONDI	TIONS	1	T _A = 25°(:	SN54AB	Г18245А	SN74AB	T18245A	UNIT
PARAMETER	1531	CONDI	IIONS	MIN	TYP [†]	MAX	MIN	MAX	MIN	MAX	UNII
VIK	$V_{CC} = 4.5 \text{ V},$	I _I = -18	3 mA			-1.2		-1.2		-1.2	V
	$V_{CC} = 4.5 \text{ V},$	I _{OH} = -	–3 mA	2.5			2.5		2.5		
\ \/a	$V_{CC} = 5 V$,	I _{OH} = -	–3 mA	3			3		3		V
VOH	$V_{CC} = 4.5 \text{ V},$	IOH = -	–24 mA	2			2				V
	$V_{CC} = 4.5 \text{ V},$	IOH = -	–32 mA	2*					2		
V _{OL}	V _{CC} = 4.5 V	I _{OL} = 4	18 mA			0.55		0.55			V
VOL	VCC = 4.5 V	I _{OL} = 6	64 mA			0.55*				0.55	V
	$V_{CC} = 5.5 \text{ V},$		DIR, OE, TCK			±1		±1		±1	μА
Η	$V_I = V_{CC}$ or GND		A or B ports			±100		±100		±100	μΑ
lН	$V_{CC} = 5.5 \text{ V},$ $V_{I} = V_{CC}$		TDI, TMS			10		10		10	μΑ
IIL	V _{CC} = 5.5 V, V _I = GND		TDI, TMS	-40		-150	-40	-150	-40	-150	μΑ
lozh [‡]	$V_{CC} = 5.5 \text{ V},$	V _O = 2	2.7 V			50		50		50	μΑ
lozL [‡]	$V_{CC} = 5.5 \text{ V},$	V _O = 0).5 V			-50		-50		-50	μΑ
lozpu	V _{CC} = 0 to 2 V, V _O = 2.7 V or 0.5 \	/	OE = 0.8 V			±50		±50		±50	μΑ
lozpd	V _{CC} = 2 V to 0, V _O = 2.7 V or 0.5 \	/	OE = 0.8 V			±50		±50		±50	μΑ
l _{off}	$V_{CC} = 0$,	V _I or V	O ≤ 4.5 V			±100		±450		±100	μΑ
ICEX	V _{CC} = 5.5 V, V _O = 5.5 V		Outputs high			50		50		50	μΑ
lo§	$V_{CC} = 5.5 \text{ V},$	V _O = 2	2.5 V	-50	-110	-200	-50	-200	-50	-200	mA
	V _{CC} = 5.5 V,	A or	Outputs high		3.5	5		5		5	
Icc	$I_{O} = 0$,	В	Outputs low		33	38		38		38	mA
	$V_I = V_{CC}$ or GND	ports	Outputs disabled		2.9	4.5		4.5		4.5	
ΔICC¶	V_{CC} = 5.5 V, One input at 3.4 V, Other inputs at V_{CC} or GND				50		50		50	μΑ	
C _i	V _I = 2.5 V or 0.5 V Control inputs			3			9.8			pF	
C _{io}	V _O = 2.5 V or 0.5 \	/	A or B ports		10			12.6			pF
Co	V _O = 2.5 V or 0.5 \	/	TDO		8			11.4			pF

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.



[†] All typical values are at $V_{CC} = 5 \text{ V}$.

[‡] The parameters I_{OZH} and I_{OZL} include the input leakage current.

[§] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

[¶] This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (test mode) (see Figure 14)

			SN54AB	SN54ABT18245A		SN74ABT18245A		
			MIN	MAX	MIN	MAX	UNIT	
fclock	Clock frequency	TCK	0	50	0	50	MHz	
t _W	Pulse duration	TCK high or low	8.1		8.1		ns	
		A, B, DIR, or OE before TCK↑	9.5		7			
t _{su}	Setup time	TDI before TCK↑	4.5		4.5		ns	
		TMS before TCK↑	3.6		3.6			
		A, B, DIR, or OE after TCK↑	0.7		0			
th	Hold time	TDI after TCK↑	0		0		ns	
		TMS after TCK↑	0.5		0.5			
t _d	Delay time	Power up to TCK↑	50*		50		ns	
t _r	Rise time	V _{CC} power up	1*		1		μs	

^{*} On products compliant to MIL-PRF-38535, these parameters are not production tested.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (normal mode) (see Figure 14)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C	CC = 5 V \(= 25°C	<u>'</u> ,	SN54AB	T18245A	SN74AB	T18245A	UNIT
	(1141 01)	(0011 01)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
tpLH	A or B	B or A	1.5	2.8	4.1	1.5	5.1	1.5	4.8	ns
t _{PHL}	AOID	BUIA	1.5	3.1	4.6	1.5	5.8	1.5	5.4	115
t _{PZH}	ŌĒ	B or A	2	4.7	5.8	2	8.1	2	7.5	no
tpZL	OE		2	4.5	6.2	2	8.5	2	8	ns
t _{PHZ}	ŌĒ	B or A	2.5	5.8	6.8	2.5	9.5	2.5	8.5	
t _{PLZ}	OL	BUIA	2.5	4.8	6	2.5	8.5	2.5	7.5	ns

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (test mode) (see Figure 14)

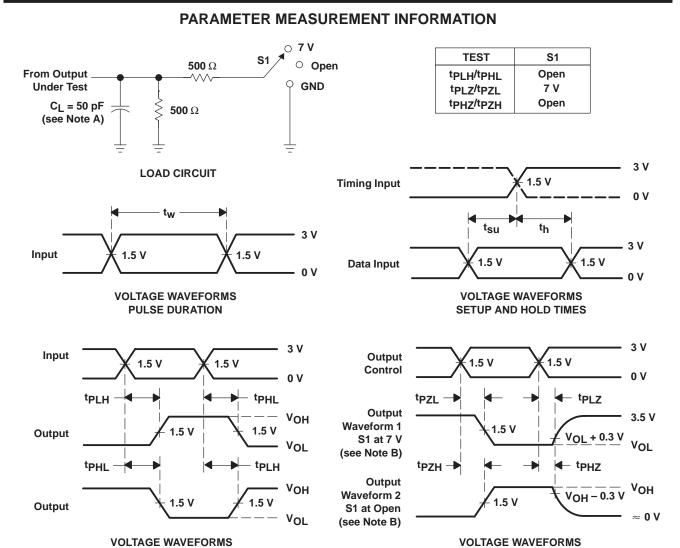
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C	CC = 5 V A = 25°C	', ;	SN54AB	T18245A	SN74AB	UNIT	
	(INFOT)	(001F01)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f _{max}	TCK↓		50	90		50		50		MHz
^t PLH	TCK↓	A or P	3	7.1	10.1	2.8	14	3	13.1	ns
^t PHL	TCK↓	A or B	3	7	10.1	3	13.8	3	12.8	
^t PLH	TCK↓	TDO	2	3.4	5	2	6.4	2	6.1	ns
^t PHL	TCK↓	100	2	3.9	5.6	2	7	2	6.5	113
^t PZH	TCK↓	A or B	4	7.5	10.6	4	14.1	4	13.4	ns
^t PZL	TON		4	7.6	10.5	4	14.3	4	13.6	
^t PZH	тск↓	TDO	2	3.8	5.5	2	7	2	6.6	
t _{PZL}	TCK↓	100	2.5	4	5.7	2.3	7.3	2.5	6.9	115
^t PHZ	TCK↓	A or B	3.5	7.7	10.8	2.9	14.4	3.5	13.6	20
t _{PLZ}	TCK↓	AUID	2.5	7.1	10.1	2.5	13.8	2.5	12.7	ns
^t PHZ	TCK↓	TDO	2	3.9	5.7	2	7.5	2	7.2	ns
t _{PLZ}	TOK↓	150	1.5	3.5	5.4	1.5	6.7	1.5	6.3	



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ENABLE AND DISABLE TIMES

LOW- AND HIGH-LEVEL ENABLING



NOTES: A. C_L includes probe and jig capacitance.

PROPAGATION DELAY TIMES

INVERTING AND NONINVERTING OUTPUTS

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 14. Load Circuit and Voltage Waveforms





10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9460102QXA	ACTIVE	CFP	WD	56	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460102QX A SNJ54ABT18245A WD	Samples
SN74ABT18245ADGGR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT18245A	Samples
SN74ABT18245ADL	ACTIVE	SSOP	DL	56	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT18245A	Samples
SN74ABT18245ADLG4	ACTIVE	SSOP	DL	56		TBD	Call TI	Call TI	-40 to 85		Samples
SN74ABT18245ADLR	ACTIVE	SSOP	DL	56	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT18245A	Samples
SN74ABT18245ADLRG4	ACTIVE	SSOP	DL	56		TBD	Call TI	Call TI	-40 to 85		Samples
SNJ54ABT18245AWD	ACTIVE	CFP	WD	56	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9460102QX A SNJ54ABT18245A WD	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.





10-Jun-2014

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54ABT18245A, SN74ABT18245A:

Catalog: SN74ABT18245A

Military: SN54ABT18245A

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ABT18245ADGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN74ABT18245ADLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ABT18245ADGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN74ABT18245ADLR	SSOP	DL	56	1000	367.0	367.0	55.0

WD (R-GDFP-F**)

CERAMIC DUAL FLATPACK

48 LEADS SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only
- E. Falls within MIL STD 1835: GDFP1-F48 and JEDEC MO-146AA

GDFP1-F56 and JEDEC MO-146AB

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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